NSN 5961-00-255-3472

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View Online at https://aerobasegroup.com/nsn/5961-00-255-3472 **Inclosure Material:** Metal and glass **Overall Length:** Between 0.240 inches and 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-76 **Component Name And Quantity:** 2 transistor **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 15.0 breakdown voltage, collector-to-emitter, base open all transistor and 40.0 breakdown voltage, collector-to-base, emitter open all transistor **Current Rating Per Characteristic:** 25.00 nanoamperes zero-gate-voltage source current preset all transistor **Power Rating Per Characteristic:** 300.0 milliwatts small-signal input power, common-collector absolute all transistor **Transfer Ratio:** 120.0 static forward current transfer ratio, common-emitter all transistor **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction **Special Features:** All transistor junction pattern arrangement: npn **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:**

N/a

Unit Of Measure:

Shelf Life:

6 uninsulated wire lead

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Demilitarization:

No

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